

SANYO Semiconductors DATA SHEET

DSB15T Diffused Junction Type Silicon Diode 1.5A Power Rectifier

Features

· Plastic molded structure.

• Peak reverse voltage: V_{RM}=-100 to -1000V.

· Average rectified current : IO=1.5A.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	DSB15TB	DSB15TC	DSB15TE	Unit
Peak Reverse Voltage	VRM		-100	-200	-400	V
Average Rectified Current	IO	Ta=60°C	1.5			
Surge Forward Current	IFSM	50Hz sine wave, 1cycle	130			
Junction Temperature	Tj		150			°C
Storage Temperature	Tstg		-40 to +150			

Parameter	Symbol	Conditions	DSB15TG	DSB15TJ	DSB15TL	Unit
Peak Reverse Voltage	VRМ		-600	-800	-1000	V
Average Rectified Current	Ю	Ta=25°C	1.5			Α
Surge Forward Current	IFSM	50Hz sine wave, 1cycle	80			Α
Junction Temperature	Tj		150			°C
Storage Temperature	Tstg		-40 to +150			°C

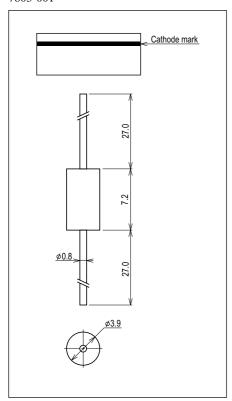
Electrical Characteristics at Ta=25°C

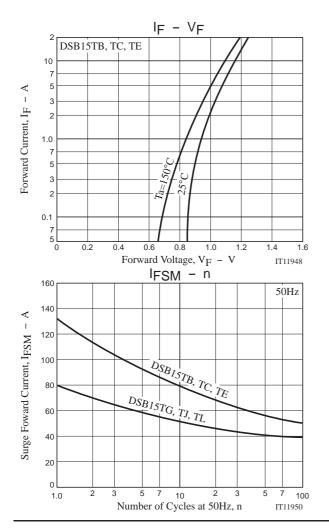
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Uill
Forward Voltage	VF	IF=1.5A (B, C, E)			0.95	V
		I _F =1.5A (G, J, L)			1.0	V
Reverse Current	IR	V _R : At each V _{RM}			-10	μΑ

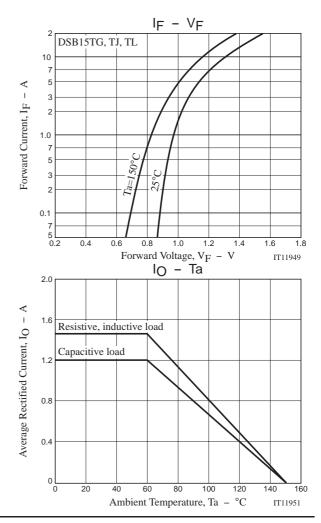
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Package Dimensions

unit : mm (typ) 7803-001







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